NCE N-Channel Super Trench Power MOSFET

Description

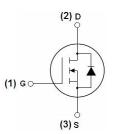
The NCEP02T10T uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

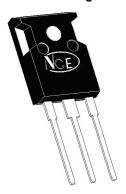
- $V_{DS} = 200V, I_{D} = 100A$ $R_{DS(ON)} < 12m\Omega @ V_{GS} = 10V$
- Excellent gate charge x R_{DS(on)} product
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



Schematic diagram



TO-247 top view

100% UIS TESTED!

100% ΔVds TESTED!

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP02T10T	NCEP02T10T	TO-247-3L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	200	V	
Gate-Source Voltage	V _G s	±20	V	
Drain Current-Continuous	I _D	100	А	
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	70.7	А	
Pulsed Drain Current	I _{DM}	400	А	
Maximum Power Dissipation	P _D	300	W	
Derating factor		2	W/℃	
Single pulse avalanche energy (Note 1)	E _{AS}	1216	mJ	
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	°C	

Thermal Characteristic

Thermal Resistance,Junction-to-Case	Reuc	0.5	°C/W
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NCEP02T10T

Electrical Characteristics (T_C=25°C unless otherwise noted)

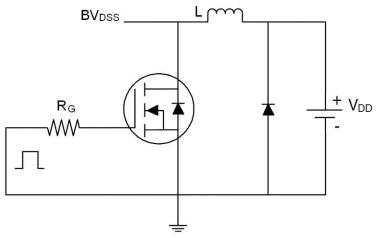
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	200		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	2.5		4.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =50A	-	9.5	12	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =50A	70	-	-	S
Dynamic Characteristics						
Input Capacitance	C _{lss}	\/ 400\/\/ 0\/	-	6000	-	PF
Output Capacitance	Coss	V _{DS} =100V,V _{GS} =0V,	-	425	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	16	-	PF
Switching Characteristics (Note 2)			•			
Turn-on Delay Time	t _{d(on)}		-	18	-	nS
Turn-on Rise Time	t _r	V_{DD} =100 V , I_{D} =50 A	-	26	-	nS
Turn-Off Delay Time	t _{d(off)}	$V_{GS}\text{=}10V,R_{G}\text{=}4.7\Omega$	-	41	-	nS
Turn-Off Fall Time	t _f		-	11	-	nS
Total Gate Charge	Qg	\/ -400\/ -504	-	87		nC
Gate-Source Charge	Q _{gs}	$V_{DS}=100V,I_{D}=50A,$	-	32		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	17.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =100A	-		1.2	V
Diode Forward Current	Is		-	-	100	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = 50	-	140		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	-	600		nC

Notes:

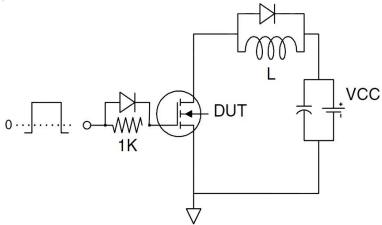
- 1. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25 Ω
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsin k, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.

Test Circuit

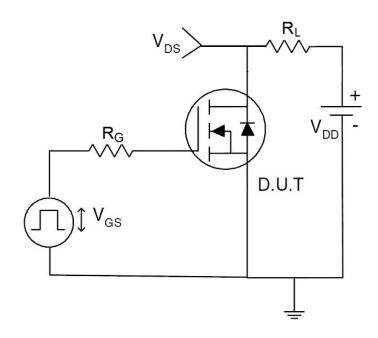
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit







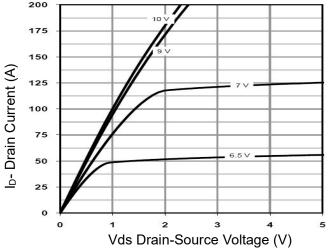


Figure 1 Output Characteristics

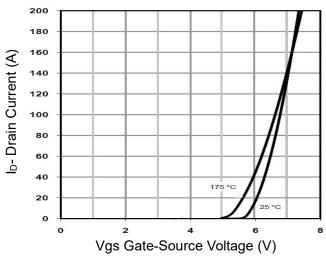


Figure 2 Transfer Characteristics

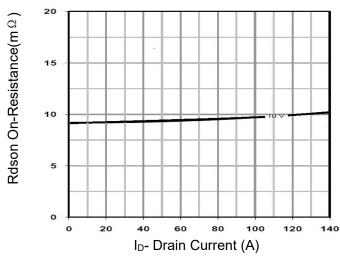


Figure 3 Rdson- Drain Current

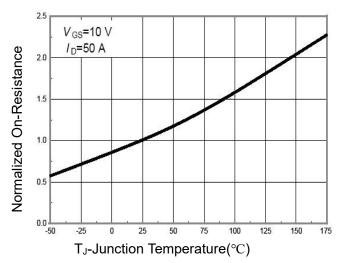


Figure 4 Rdson-JunctionTemperature

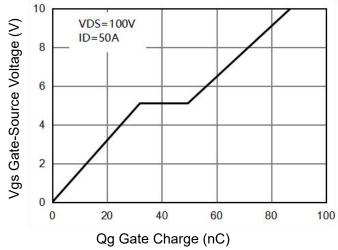


Figure 5 Gate Charge

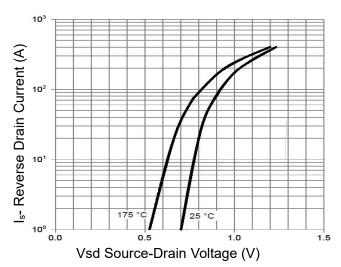


Figure 6 Source- Drain Diode Forward



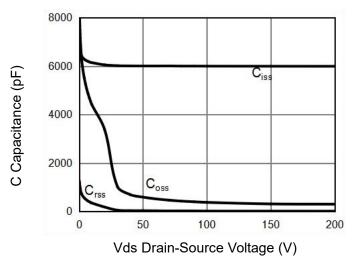


Figure 7 Capacitance vs Vds

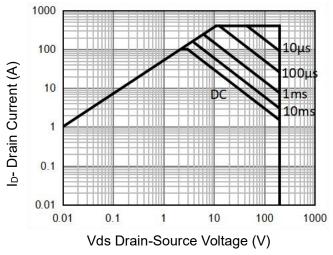


Figure 8 Safe Operation Area

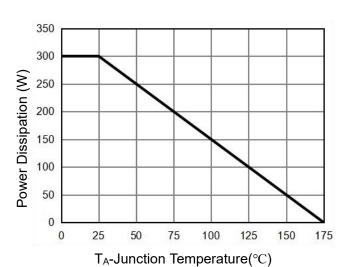


Figure 9 Power De-rating

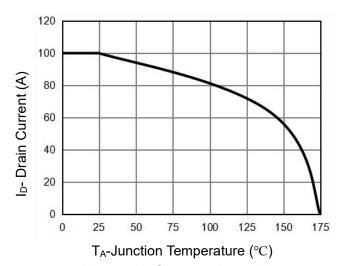


Figure 10 Current De-rating

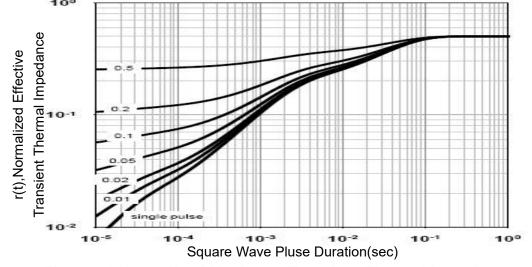
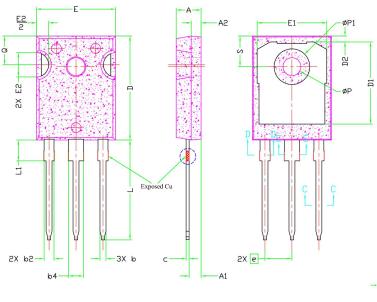


Figure 11 Normalized Maximum Transient Thermal Impedance

TO-247 Package Information







Section C--C,D--D,E--E

e) Albei				
SYMBOL	MIN.	NOM.	MAX.	NOTES
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
b	1.12	1.20	1.33	
b1	1.12	1,20	1,28	
b2	1,91	2,00	2,39	6
b3	1.91	2.00	2.34	
b4	2.87	3.00	3.22	6, 8
b5	2.87	3.00	3.18	
С	0.55	0.60	0.69	6
c1	0.55	0.60	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
е	5.44BSC			
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ØP	3.56	3.61	3.65	7
ØP1	7.19REF.			
Q	5.39	5.79	6.20	
s	6.04	6.17	6.30	

- Note:

 1. Package Reference: JEDEC TO247, Variation AD.

 2. All Dimensions Are In mm.

 3. Slot Required, Noteh May Be Rounded

 4. Dimension D & E Do Not Include Mold Flash. Mold Flash Shall Not Exceed 0.127mm Pre Side. These Dimensions Are Measured At The Outermost Extreme Of The Plastis Body.

 5. Thermal Pad Contour Optional Within Dimension D1 & E1.

 6. Lead Finish Uncontrolled In L1.

 7. ØP To Have A Maximum Draft Angle Of 1.5° To The Top Of The Part With A Maximum Hole Diameter Of 3.91 mm.

 8. Dimension "b2" And "b4" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.10mm Total In Excess Of "b2" And "b4" Dimension At Maximum Material Condition.

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NCEP02T10T

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